

2MBI200VH-120-50

IGBT Modules

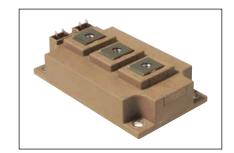
IGBT MODULE (V series) 1200V / 200A / 2 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines



Maximum Ratings and Characteristics

■ Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items	Symbols	Conditions		Maximum ratings	Units	
Collector-Emitter voltage	Vces			1200		
Gate-Emitter voltage	V _{GES}			±20	V	
Collector current	la.	Continuous	Tc=100°C	200		
	Ic		Tc=25°C	240		
	Ic pulse	1ms		400	Α	
	-IC					
	-lc pulse	1ms		400		
Collector power dissipation	Pc	1 device	1 device		W	
Junction temperature	Tj	ri l		175		
Operating junction temperature (under switching condit	tions) T _{jop}			150	°C	
Case temperature	Tc			125	C	
Storage temperature	Tstg			-40 ~ +125		
Isolation voltage between terminal and copper base	(*1) V _{iso}	AC : 1min.		2500	VAC	
Mounting (*2)				6.0	NI ma	
Screw torque Terminals (*3)	-			5.0	Nm	

Note *1: All terminals should be connected together during the test. Note *2: Recommendable Value : 3.0-6.0 Nm (M5 or M6) Note *3: Recommendable Value : 2.5-5.0 Nm (M6)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

ems	Cumbala	Symbols Conditions		Characteristics		I I sold on	
ems	Symbols			min.	typ.	max.	Units
Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	2.0	mA
Gate-Emitter leakage current	Iges	$V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	400	nA
Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 200mA		6.0	6.5	7.0	V
Collector-Emitter saturation voltage	V	V _{GE} = 15V I _C = 200A	Tj=25°C	-	1.95	2.40	V
	V _{CE} (sat)		Tj=125°C	-	2.25	-	
	(terminal)		Tj=150°C	-	2.30	-	
	V _{CE} (sat)		Tj=25°C	-	1.75	2.15	
			Tj=125°C	-	2.05	-	
	(chip)		Tj=150°C	-	2.10	-	
Internal gate resistance	R _{g(int)}	-		-	3.8	-	Ω
Input capacitance	Cies	Vce = 10V, Vge = 0V, f = 1MHz		-	18.2	-	nF
Input capacitance Turn-on time	ton	V _{cc} = 600V, I _c = 200A V _{GE} = ±15V, R _G = 2.7Ω Tj = 150°C, Ls =30nH		-	0.60	-	µsec
	tr			-	0.20	-	
	tr (i)			-	0.05	-	
Turn-off time	toff			-	0.80	-	
	tf			-	0.08	-	
Forward on voltage	VF	V _{GE} = 0V I _F = 200A	Tj=25°C	-	1.85	2.35	V
	(terminal)		Tj=125°C	-	2.00	-	
	(terminar)		Tj=150°C	-	1.95	-	
	VF		Tj=25°C	-	1.70	2.15	
	1		Tj=125°C	-	1.85	-	
	(chip)		Tj=150°C	-	1.80	-	
Reverse recovery time	trr	I _F = 200A	-	-	0.15	-	use

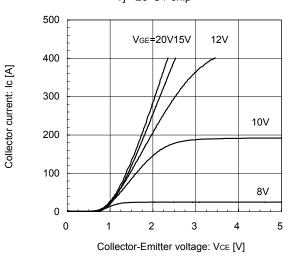
■ Thermal resistance characteristics

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Items	Symbols	Conditions	Characteristics			Units	
		Conditions	min.	typ.	max.	Ullits	
Thermal resistance (1device)	Rth(j-c)	IGBT	-	-	0.135	°C/W	
		FWD	-	-	0.200		
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.0250	-		

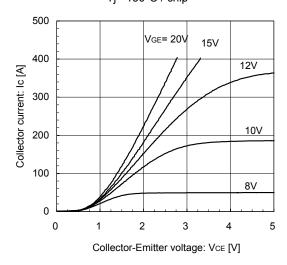
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

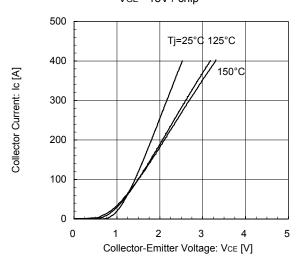
Collector current vs. Collector-Emitter voltage (typ.) Tj= 25°C / chip



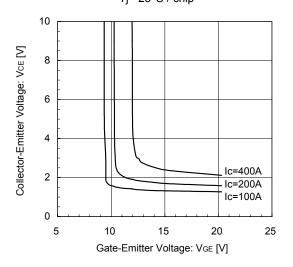
Collector current vs. Collector-Emitter voltage (typ.) Tj= 150°C / chip



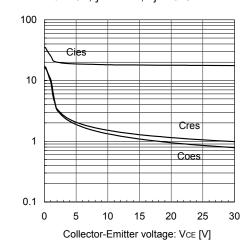
Collector current vs. Collector-Emitter voltage (typ.) VGE= 15V / chip



Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) Tj= 25°C / chip

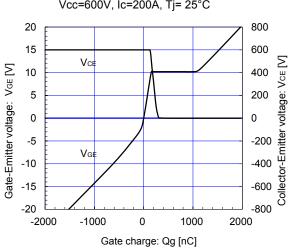


Gate Capacitance vs. Collector-Emitter Voltage (typ.) $V_{GE}=0V, f=1MHz, Tj=25^{\circ}C$

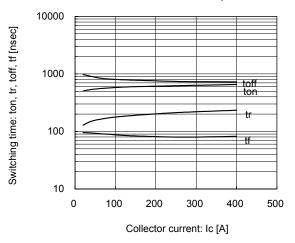


Gate Capacitance: Cies, Coes, Cres [nF]

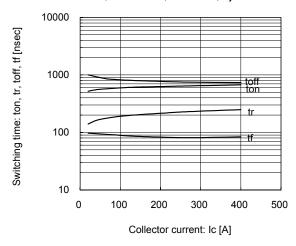
Dynamic Gate Charge (typ.) Vcc=600V, Ic=200A, Tj= 25°C



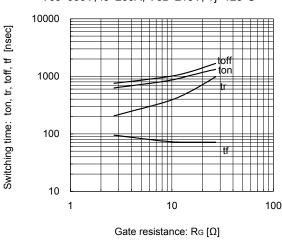
Switching time vs. Collector current (typ.) Vcc=600V, VgE= \pm 15V, Rg= 2.7Ω , Tj= 125° C



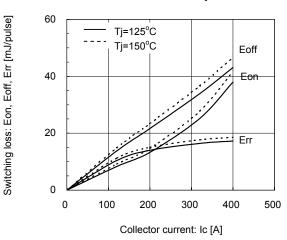
Switching time vs. Collector current (typ.) Vcc=600V, $VgE=\pm15V$, $Rg=2.7\Omega$, $Tj=150^{\circ}C$



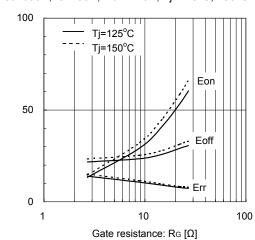
Switching time vs. Gate resistance (typ.) Vcc=600V, Ic=200A, VgE=±15V, Tj=125°C



Switching loss vs. Collector current (typ.) Vcc=600V, VgE=±15V, Rg=2.7Ω, Tj=125°C, 150°C

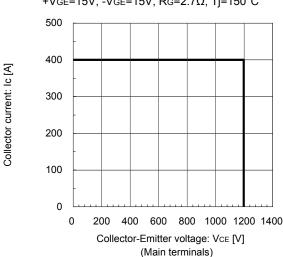


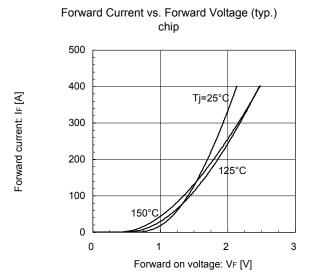
Switching loss vs. Gate resistance (typ.) Vcc=600V, Ic=200A, VgE=±15V, Tj=125°C, 150°C

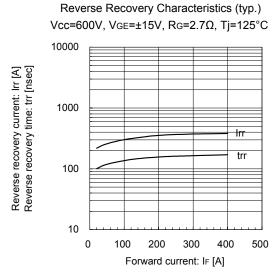


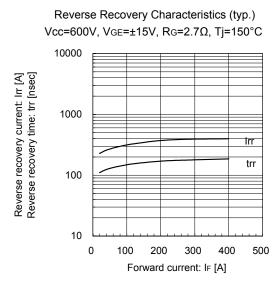
Switching loss: Eon, Eoff, Err [mJ/pulse]

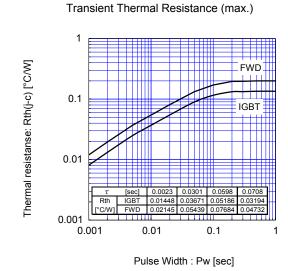
Reverse bias safe operating area (max.) $+V_{GE}=15V$, $-V_{GE}=15V$, $R_{G}=2.7\Omega$, $T_{J}=150^{\circ}C$

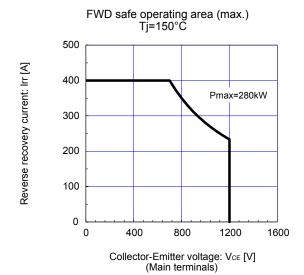






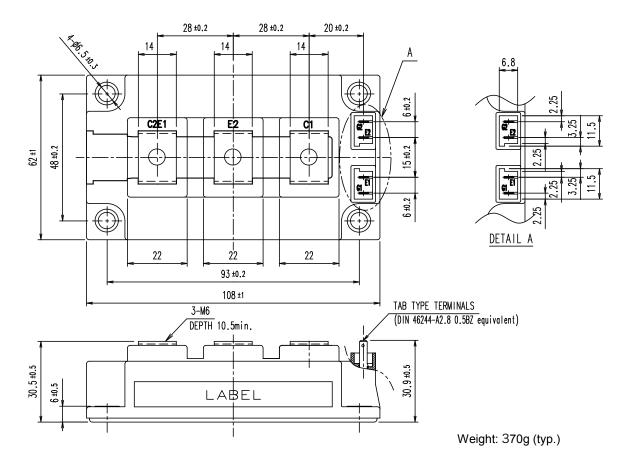




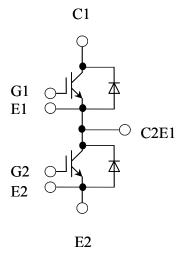


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■ Outline Drawings (Unit: mm)



■ Equivalent Circuit



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